

**Preliminary** TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

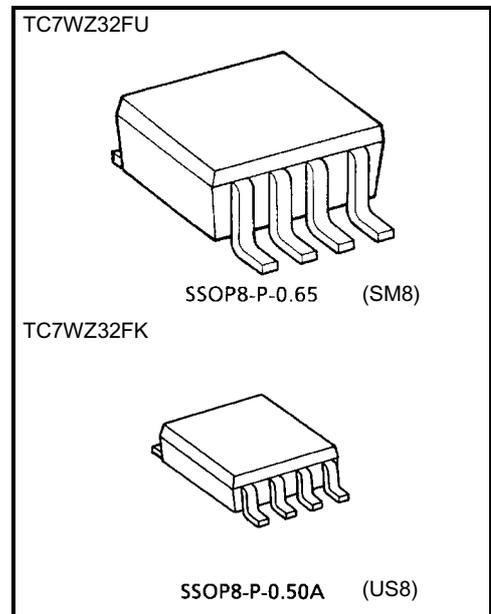
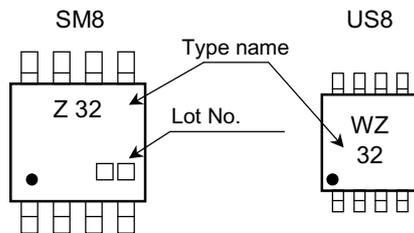
# TC7WZ32FU, TC7WZ32FK

2 Input or Gate

## Features

- High output drive:  $\pm 24$  mA (min) @ $V_{CC} = 3$  V
- Super high speed operation:  $t_{pd}$  2.4 ns (typ.) @ $V_{CC} = 5$  V, 50 pF
- Operation voltage range:  $V_{CC (opr)} = 1.65\sim 5.5$  V
- Latch-up performance:  $\pm 500$  mA or more
- ESD performance:  $\pm 200$  V or more (EIAJ)  
 $\pm 2000$  V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V  $V_{CC}$ .

## Marking

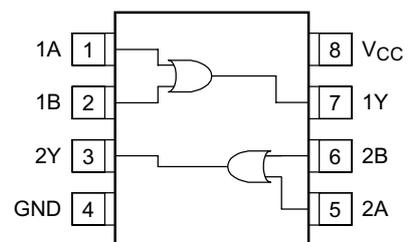


Weight  
 SSOP8-P-0.65 : 0.02 g (typ.)  
 SSOP8-P-0.50A : 0.01 g (typ.)

## Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5~6	V
DC input voltage	$V_{IN}$	-0.5~6	V
DC output voltage	$V_{OUT}$	-0.5~6	V
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	-20	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 50$	mA
Power dissipation	$P_D$	300 (SM8) 200 (US8)	mW
Storage temperature	$T_{stg}$	-65~150	°C
Lead temperature (10s)	$T_L$	260	°C

## Pin Assignment (top view)



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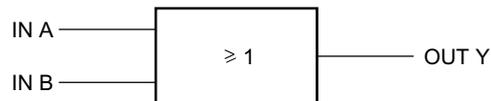
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## Truth Table

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

## Logic Diagram



## Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	1.65~5.5	V
		1.5~5.5 (Note 1)	
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~5.5 (Note 2)	V
		0~ $V_{CC}$ (Note 3)	
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	$d_t/d_v$	0~20 ( $V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$ , 2.5 $\text{V} \pm 0.2\text{ V}$ )	ns/V
		0~10 ( $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ )	
		0~5 ( $V_{CC} = 5.5\text{ V} \pm 0.5\text{ V}$ )	

Note 1: Data retention only

Note 2:  $V_{CC} = 0\text{ V}$

Note 3: High or low state

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- The information contained herein is subject to change without notice.

## Electrical Characteristics

### DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
					V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
Input voltage	High level	V <sub>IH</sub>	—	1.65~1.95	0.75 × V <sub>CC</sub>	—	—	0.75 × V <sub>CC</sub>	—	V	
				2.3~5.5	0.7 × V <sub>CC</sub>	—	—	0.7 × V <sub>CC</sub>	—		
	Low level	V <sub>IL</sub>	—	1.65~1.95	—	—	0.25 × V <sub>CC</sub>	—	0.25 × V <sub>CC</sub>		
				2.3~5.5	—	—	0.3 × V <sub>CC</sub>	—	0.3 × V <sub>CC</sub>		
Output voltage	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.65	1.55	1.65	—	1.55	—	V
					2.3	2.2	2.3	—	2.2	—	
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				I <sub>OH</sub> = -4 mA	1.65	1.29	1.52	—	1.29	—	
					2.3	1.9	2.15	—	1.9	—	
					3.0	2.4	2.8	—	2.4	—	
					4.5	3.8	4.2	—	3.8	—	
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0	0.1	—	0.1	
					2.3	—	0	0.1	—	0.1	
					3.0	—	0	0.1	—	0.1	
					4.5	—	0	0.1	—	0.1	
				I <sub>OL</sub> = 4 mA	1.65	—	0.08	0.24	—	0.24	
					2.3	—	0.1	0.3	—	0.3	
				I <sub>OL</sub> = 8 mA	3.0	—	0.15	0.4	—	0.4	
					3.0	—	0.22	0.55	—	0.55	
				I <sub>OL</sub> = 16 mA	3.0	—	0.22	0.55	—	0.55	
					4.5	—	0.22	0.55	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	0~5.5	—	—	±1	—	±10	μA	
Power off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	0.0	—	—	1	—	10	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND	1.65~5.5	—	—	1	—	10	μA	

**AC Characteristics (unless otherwise specified, Input:  $t_r = t_f = 3$  ns)**

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit	
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
Propagation delay time	t <sub>pLH</sub>	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 1 MΩ	1.8 ± 0.15	2.0	5.8	10.5	2.0	11.0	ns
			2.5 ± 0.2	1.0	3.5	5.8	1.0	6.2	
	3.3 ± 0.3		0.8	2.6	3.9	0.8	4.3		
	5.0 ± 0.5		0.5	2.6	3.1	0.5	3.3		
	t <sub>pHL</sub>	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 Ω	3.3 ± 0.3	1.2	3.2	4.8	1.2	5.2	
			5.0 ± 0.5	0.8	2.4	3.7	0.8	4.0	
Input capacitance	C <sub>IN</sub>	—	0~5.5	—	3.0	—	—	pF	
Power dissipation capacitance	C <sub>PD</sub>	(Note)	3.3	—	20	—	—	—	pF
			5.5	—	26	—	—	—	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

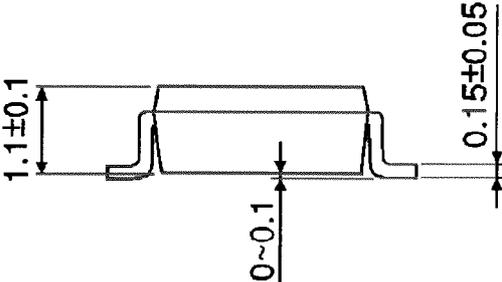
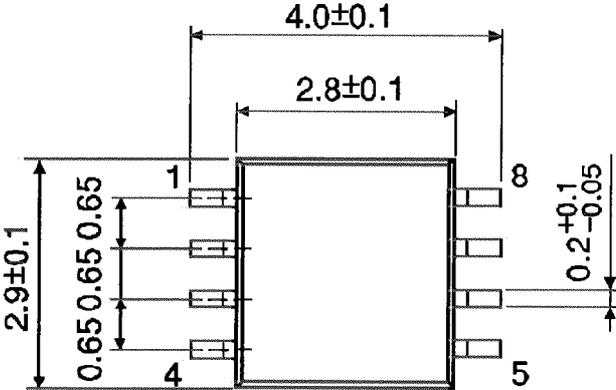
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$$

Package Dimensions

SSOP8-P-0.65

Unit : mm

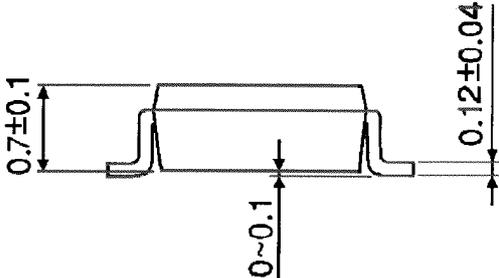
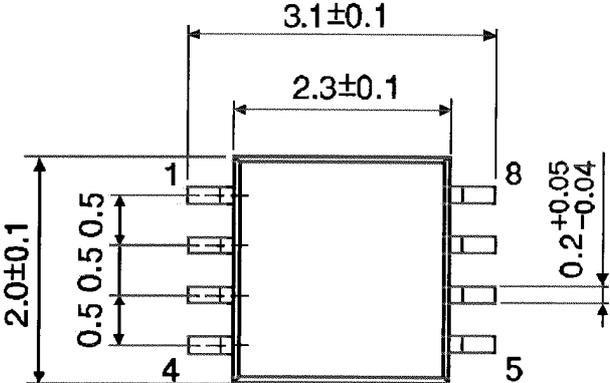


Weight: 0.02 g (typ.)

**Package Dimensions**

SSOP8-P-0.50A

Unit : mm



Weight: 0.01 g (typ.)